

NCE N-Channel Super Trench II Power MOSFET

Description

The series of devices uses **Super Trench II** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{\text{DS(ON)}}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

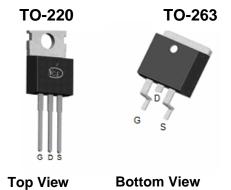
Application

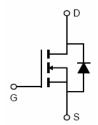
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

General Features

- V_{DS} =100V, I_D =130A $R_{DS(ON)}$ =3.7m Ω , typical (TO-220)@ V_{GS} =10V $R_{DS(ON)}$ =3.55m Ω , typical (TO-263)@ V_{GS} =10V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!





Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP040N10	NCEP040N10	TO-220-3L			
NCEP040N10D	NCEP040N10D	TO-263-2L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	130	Α
Drain Current-Continuous(T _C =100℃)	I _D (100℃)	100	А
Pulsed Drain Current ^(Note 1)	I _{DM}	520	А
Maximum Power Dissipation	P _D	210	W
Derating factor		1.4	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	750	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}\!\mathbb{C}$



Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{ heta JC}$	0.71	°C/W

Electrical Characteristics (T_C=25°C unless otherwise noted)

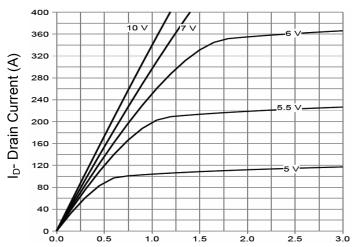
Parameter	Parameter Symbol Condition		n	Min	Тур	Max	Unit
Off Characteristics				•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA		100		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V,V _{GS} =0V		-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V		-	-	±100	nA
On Characteristics (Note 3)				I.			
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =2	50µA	2	3	4	V
Drain Course On State Desistance	TO-220	TO-220	-	3.7	4.0	mΩ	
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =65A	TO-263		3.55	4.0	mΩ
Forward Transconductance	g Fs	V _{DS} =5V,I _D =6	65A		130	-	S
Dynamic Characteristics (Note4)				•			
Input Capacitance	C _{lss}	V _{DS} =50V,V _{GS} =0V, F=1.0MHz		-	6300	-	PF
Output Capacitance	Coss			-	560	-	PF
Reverse Transfer Capacitance	C _{rss}			-	40	-	PF
Switching Characteristics (Note 4)				•			
Turn-on Delay Time	t _{d(on)}			-	23	-	nS
Turn-on Rise Time	t _r	V _{DD} =50V,I _D =6	65A,	-	15	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =3 Ω		-	48	-	nS
Turn-Off Fall Time	t _f			-	16	-	nS
Total Gate Charge	Qg	\/ -F0\/ -/	25.4	-	110	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =50V,I _D =65A, V _{GS} =10V		-	33		nC
Gate-Drain Charge	Q_{gd}			-	30		nC
Drain-Source Diode Characteristics							•
Diode Forward Voltage (Note 3)	V_{SD}	V _{GS} =0V,I _S =6	65A	-		1.2	V
Diode Forward Current (Note 2)	Is			-	-	130	Α
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F =65A		-	70	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)		-	117	-	nC
	•						•

Notes:

- ${\bf 1.}\ {\bf Repetitive}\ {\bf Rating:}\ {\bf Pulse}\ {\bf width}\ {\bf limited}\ {\bf by}\ {\bf maximum}\ {\bf junction}\ {\bf temperature}.$
- 2. Surface Mounted on FR4 Board, t \leq 10 sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25 $^{\circ}\text{C}$,V $_{\text{DD}}$ =50 V,V $_{\text{G}}$ =10 V,L=0.5 mH,Rg=25 Ω

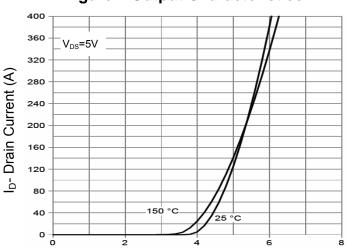


Typical Electrical and Thermal Characteristics



Vds Drain-Source Voltage (V)

Figure 1 Output Characteristics



Vgs Gate-Source Voltage (V)

Figure 2 Transfer Characteristics

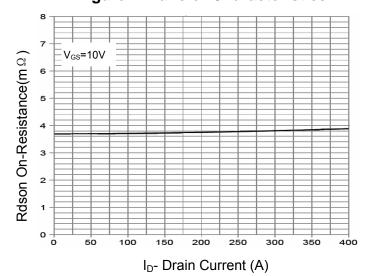
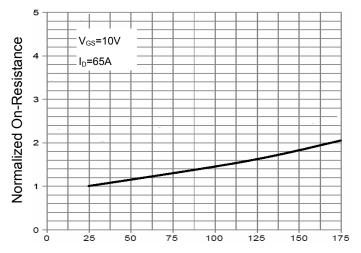


Figure 3 Rdson- Drain Current



T_J-Junction Temperature(°C)

Figure 4 Rdson-Junction Temperature

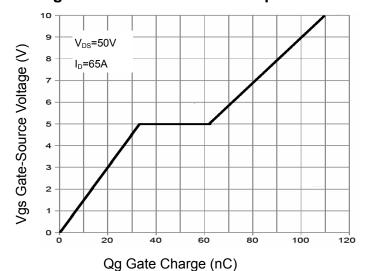
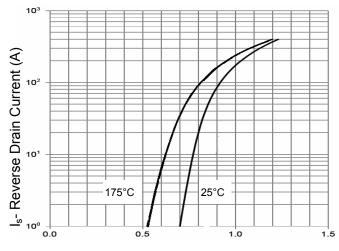


Figure 5 Gate Charge



Vsd Source-Drain Voltage (V)

Figure 6 Source- Drain Diode Forward



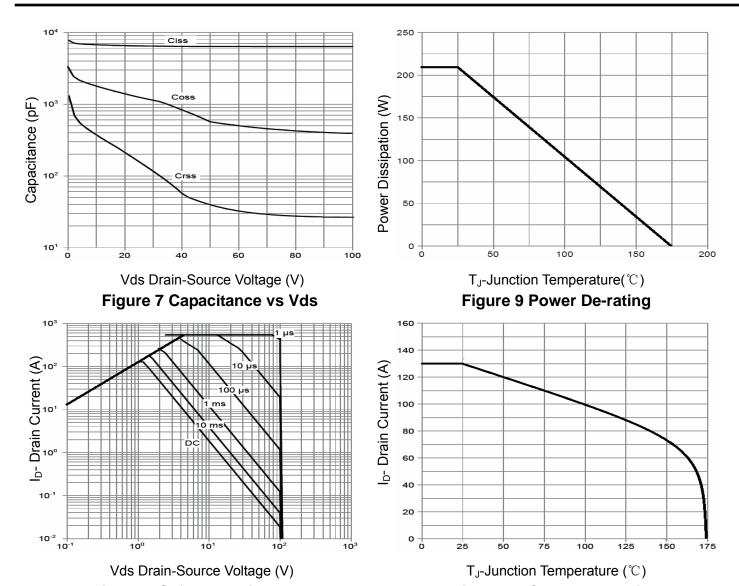


Figure 8 Safe Operation Area

Figure 10 Current De-rating

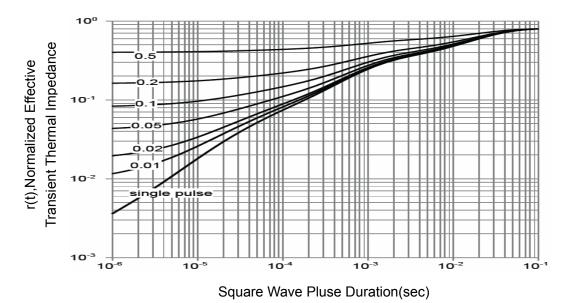
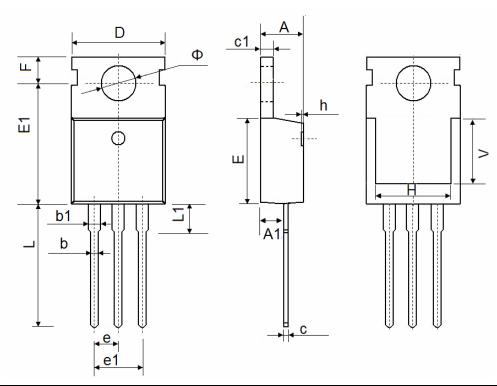


Figure 11 Normalized Maximum Transient Thermal Impedance



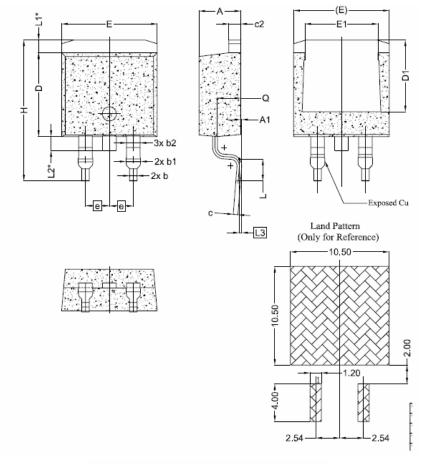
TO-220-3L Package Information



Cumbal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.54	0 TYP.	0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	6.900 REF.		0.276 REF.		
Ф	3.400	3.800	0.134	0.150	



TO-263-2L Package Information



SYMBOL	DIMENSIONS				
STIMBOL	MIN.	NOM.	MAX.		
А	4.24	4.44	4.64		
A1	0.00	0.10	0.25		
b	0.70	0.80	0.90		
b1	1.20	1.55	1.75		
b2	1,20	1,45	1,70		
С	0.40	0.50	0.60		
c2	1,15	1,27	1,40		
D	8.82	8.92	9.02		
D1	6.86	7.65	_		
E	9.96	10.16	10.36		
E1	6.89	7.77	7.89		
е	2,54 BSC				
Н	14,61	15,00	15,88		
L	1.78	2.32	2.79		
L1	1.36 REF.				
L2	1.50 REF.				
L3	0.25 BSC				
Q	2.30	2.48	2.70		



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